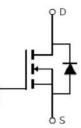


Main Product Characteristics:

V _{DSS}	30V			
R _{DS} (on)	3.9m (typ.)			
ID	76A			





G

TO-252

Schematic Diagram

Features and Benefits:

Advanced MOSFET process technology Special designed for PWM, load switching and general purpose applications Ultra low on-resistance with low gate charge Fast switching and reverse body recovery 150 operating temperature



Description:

It utilizes the latest processing techniques to achieve the high cell density and reduces the on-resistance with high repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in power switching application and a wide variety of other applications.

Absolute Max Rating:

Symbol	Max.	Units	
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V	76	
I _D @ T _C = 100°C	Continuous Drain Current, V _{GS} @ 10V	53	А
Ідм	Pulsed Drain Current	304	
P _D @T _C = 25°C	Power Dissipation	53	W
V _{DS}	Drain-Source Voltage	30	V
V _{GS}	Gate-to-Source Voltage	± 20	V
Tj Tstg	Operating Junction and Storage Temperature Range	-55 to +150	°C

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Thermal Resistance

Symbol	Characterizes	Тур.	Max.	Units
R JC	Junction-to-case	_	2.8	/W

Electrical Characterizes @T_A=25 unless otherwise specified

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source breakdown voltage	30	—	_	V	$V_{GS}=0V,\ I_D=250\mu A$

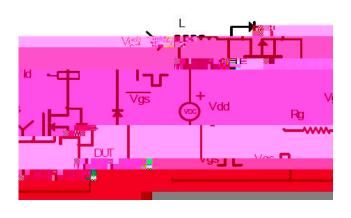
R_{DS(on)} Static Drain-to-Source on-resis fi

, 9_{*}

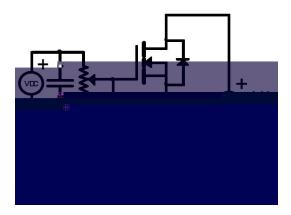


Test Circuits and Waveforms

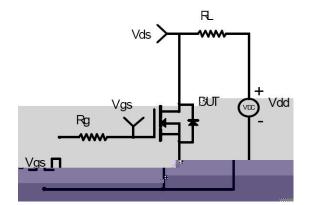
EAS Test Circuit:



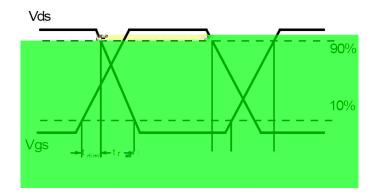
Gate Charge Test Circuit:



Switching Time Test Circuit:



Switching Waveforms:



Notes:

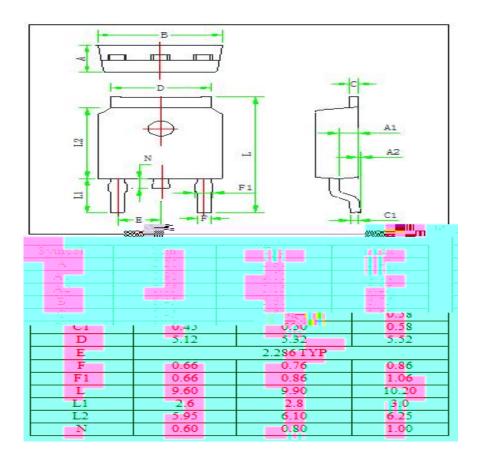
Calculated continuous current based on maximum allowable junction temperature.

Repetitive rating; pulse width limited by max. junction temperature.

The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance.



Mechanical Data





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